### MVR5510AMBAHES – NXP Standard

Configuration for S32G based applications using LPDDR4

### Configuration report for ASILB OTP program ID: AH rev B

## Rev. 1.1 - Sept 8 2021

Report

### 1 General description

The VR5510 is an automotive multi-output power management integrated circuit, with focus on Gateway, V2X and Infotainment applications. It includes multiple high efficiency switch mode and linear voltage regulators. It offers external frequency synchronization input and output, for optimized system EMC performance.

The VR5510 includes enhanced safety features, with fail-safe output, becoming a full part of a safety-oriented system partitioning, covering both ASILB and ASILD safety integrity level.It is developed in compliance with ISO 26262 standard.

### 2 Features and benefits

- 60V DC maximum input voltage
- Configurable VPRE synchronous buck controller with external MOSFETs.
- Configurable Single/dual-Phase Low voltage buck converters with DVS capability
- Configurable Low voltage integrated synchronous BUCK3 converter
- BOOST converter with integrated low side switch
- 3x linear voltage regulators with configurable Output Voltage
- High voltage linear regulator (HVLDO) with LDO and Switch mode operation
- EMC optimization with frequency tuning, clock synchronization, frequency spread spectrum and slew rate control
- Low power standby mode (40uA quiescent Current)
- 2x input pins for wake-up detection and battery voltage sense
- Device control via I2C interface with CRC (up to 3.4 MHz)
- Selectable OTP Default configuration

## 3 Applications

- Automotive Infotainment
- High End Industrial

### 4 Ordering information

#### **Table 1. Ordering information**

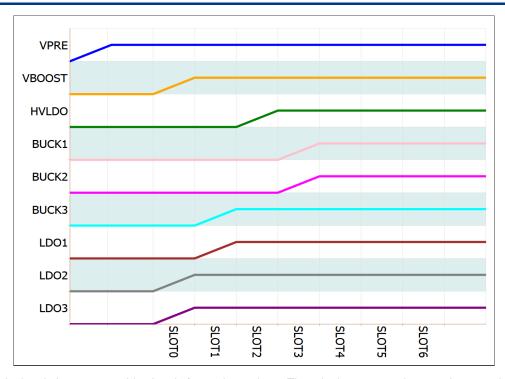
Type number <sup>[1]</sup>	Package	Package				
	Name	Description	Version			
MVR5510AMBAHES	QFN56-EP	QFN56 plastic thermally enhanced very thin quad flat non-leaded package. Wettable flanks; 56 terminals; 0.5mm pitch,8mmx8mmx0.85mm body	SOT684-21			

[1] To order parts in tape and reel, add the R2 suffix to the part number.



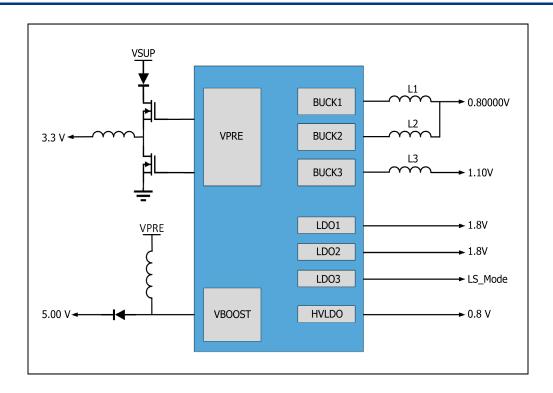
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# 5 Power-up sequence summary



The signals depicted above are enable signals for each regulator. They don't represent the actual ramp voltage

# 6 Hardware configuration diagram



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# 7 System configuration

See VR5510 datasheet for parametric details. The OTP configuration summary for AH sequence ID is provided in Tables below.

**Table 2. Device OTP configuration** 

Functional block	Feature	OTP selection
	Main I2C Address	0x20
	VSUP UV threshold	4.9 V
	Auto Re-try Enable	Enabled (default)
	Auto Re-try Timeout	4 s (default)
Device Configuration	Number of Retries	Infinite Retry (default)
Device Configuration	PLL Enable	Disabled (default)
	Clock 1 Divider	2.22 MHz (default)
	Clock 2 Divider	455 KHz (default)
	Thermal Warning TH	105 °C (default)
	Deep Sleep Enable	DSM Disabled (default)
	PWRON2 Control	Not Required
	AMUX/FOUT Select	AMUX Enabled (default)
	PSYNC Enable	PSYNC Disabled (default)
	PSYNC Mode	Sync 2 x VR5510
IO Configuration	PSYNC Power Down Ctrl	Ignore for PwrDown
10 Configuration	Standby Transition Timer	Enabled (default)
	Standby Discharge TH	75 mV (default)
	Standby Polarity	Active Low (default)
	Standby PGOOD Enable	Enabled (default)
	PSYNC PGOOD Ext	Disabled

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Ext Standby Discharge	Disabled
Standby PGOOD Delay	400us
VDDIO Supply Seletion	LDO3 (default)
Multiphase Configuration	Dual Phase

#### **Table 3. Voltage Regulators Configuration**

Functional block	Feature	OTP selection	
	VPRE Voltage	3.3 V (default)	
	Slope Compensation	41.4 mV/us	
	VPRE Standby Output Ctrl	Set by VPREV_STBY (I2C)	
	ILIM sense Voltage	120 mV	
	VPRE HighSide pull down Slew Rate Ctrl	PD / 520 mA (455 KHz default value)	
VPRE Configuration	VPRE HighSide pull up Slew Rate Ctrl	PU / 520mA (455 KHz default value)	
VI IVE Configuration	VPRE LowSide Slew Rate Ctrl	PU / PD / 900 mA (default value)	
	Soft Start Ramp	2 mV/us (default)	
	VPRE Off Time	80 ns	
	TON in PFM	550 ns (default value)	
	TON Min	45 ns	
	Turn OFF Delay	250 us	
	VBOOST Voltage	5.00 V (default)	
	Slope Compensation	67 mV/us (default)	
VBOOST Configuration	Minimum TON	60 ns (default)	
v booti oomigaration	Current Limit	2.25 A (default)	
	Low Side Slew Rate Ctrl	500 V/us (default)	
	Input Path to BOS	Enabled (default)	

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Compensation Capacitor	125 pF (default)
Compensation Resistor	500 kΩ (default)

### **Table 4. BUCK Regulators**

Functional block	Feature	OTP selection
	Output Voltage	0.80 V
	Current Limit	3.6 A
BUCK1/2 - Dual Phase	Output Inductor	1 uH(default)
	DVS Ramp of BUCK12	15.6 mV/us (power up) / 10.4 mV/us (power down)
	Transconductance	65 umho
	Output Voltage	1.10 V
	Current Limit	3.6 A
BUCK3	Output Inductor	1 uH(default)
	Ramp	3.47 mV/us (power up/down)
	Transconductance	65 umho
	R Comp	56 ΚΩ

#### **Table 5. LDO Regulators**

Functional block	Feature	OTP selection	
LDO1 Regulator	Output Voltage	1.8 V	
	Current Limit	400 mA (default)	
LDO2 Regulator	Output Voltage	1.8 V	
	LDO Mode	LDO Mode (default)	
LDO3 Regulator	Output Voltage	LS_Mode	
	LDO Mode	Load Switch (default)	

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#### **Table 6. HVLDO Regulator**

Functional block	Feature	OTP selection	
	HVLDO Voltage	0.8 V (default)	
HVLDO Regulator	Transition Mode	Switch in Normal / LDO in Standby (default)	
	Sequence Control	Follows HVLDOS_OTP slot	

#### **Table 7. Voltage Sequence and Timing Configuration**

Regulator	Sequence	Enabled	Phase Delay	Clock	TSD Event	
VPRE	Auto-enabled	Enabled	No delay	CLK2		
VBOOST	Slot 0	Enabled	No delay	CLK1	Shutdown + DFS	
BUCK1	Slot 3	Enabled	1 clock delay	CLK1	Shutdown + DFS	
BUCK2	Slot 3	Enabled	2 clock delay	CLK1	Shutdown + DFS	
вискз	Slot 1	Enabled	3 clock delay	CLK1	Shutdown + DFS	
LDO1	Slot 1	Enabled			Shutdown + DFS	
LDO2	Slot 0	Enabled			Shutdown + DFS	
LDO3	Slot 0	Enabled			Shutdown + DFS	
HVLDO	Slot 2	Enabled			Shutdown + DFS	
SLOT Width	250 us					

#### **Table 8. Safety State Machine Configuration**

Functional block	Feature	OTP selection	
	FailSafe I2C Address	0x21	
	8sec Timer to DFS	Timer Enabled	
Safety Configuration	ABIST1 to RSTB delay	No Delay (default)	
	VCOREMON SVS Clamp Limit	16 steps available (default)	
	VCOREMON SVS Offset Type	Negative offset (default)	

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### Configuration report for ASILB OTP program ID: AH rev B

PGOOD assert with RSTB	PGOOD Asserts with RSTB Fault (default)
HVLDO Mode Select	Switch Mode (default)
WDI Polarity	Falling Edge
WDI on FCCU1	WDI Disabled (default)
STANDBY Mode	STANDBY Enabled (default)
STANDBY Polarity	Active Low in standby mode (default)
STANDBY Request Path	I2C + STBY Pin Transition (default)
STANDBY Window	STBY Window Enabled (default)
WD Init Timeout	1024 ms
Fault Recovery Mode	Disabled
WD Selection	Simple WD
WD Monitoring	WD Enabled (default)
FCCU Monitoring	FCCU Enabled (default)
LBIST Enable	LBIST Disabled
	HVLDO Mode Select  WDI Polarity  WDI on FCCU1  STANDBY Mode  STANDBY Polarity  STANDBY Request Path  STANDBY Window  WD Init Timeout  Fault Recovery Mode  WD Selection  WD Monitoring  FCCU Monitoring

**Table 9. Voltage Monitoring** 

	VMONEN	Voltage	UV_TH	OV_TH	UV Dbnc	OV Dbnc	PGOOD Ctrl	ABIST Ctrl
VCOREMON	Enabled	0.80000V	95.5%	106%	25 us	25 us	PGOOD Assigned	ABIST performed
VDDIOMON	Enabled	3.3 V	95%	105%	25 us	25 us	PGOOD Assigned	ABIST performed
HVLDOMON	Enabled	0.8 V	93%	107%	25 us	25 us	PGOOD Assigned	ABIST performed
VMON1	Enabled	0.8 V	95%	105%	25 us	25 us	PGOOD Assigned	ABIST performed
VMON2	Enabled	0.8 V	97.5%	104.5%	25 us	25 us	PGOOD Assigned	ABIST performed
VMON3	Enabled	0.8 V	95.5%	106%	25 us	25 us	PGOOD Assigned	ABIST performed
VMON4	Enabled	0.8 V	95%	105%	25 us	25 us	PGOOD Assigned	ABIST performed

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# **Revision History**

Date	OTP Rev / PDF Rev	OTP Changes from the first revision
Oct 21 2020	Rev A / Rev 1.0	Initial prototype release of the OTP settings
Mar 3 2021	Rev B / Rev 1.0	Production release of the OTP  1. BUCK3 Non DVS Ramp: Changed to 3.47mV/us (power up/down) from 10.42mV/us (power up/down)  2. Standby PGOOD Release Delay: Changed to 400us from 300us  3. LDO1 Sequence: Changed to Slot 1 from Slot 0
Sept 8 2021	Rev B / Rev 1.1	Fixed typographical errors in the previously released rev B production OTP